



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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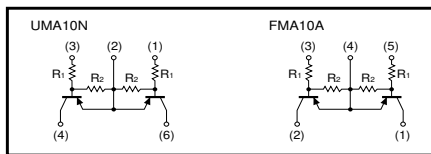
General purpose (dual digital transistors)

UMA10N / FMA10A

●Features

- 1) Two DTA113Z chips in a UMT package.

●Equivalent circuits



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Supply voltage	V _{CC}	-50	V
Input voltage	V _{IN}	-10	V
Output current	I _O	5	mA
Power dissipation	P _d	-100	mW *1
		150(TOTAL)	
Junction temperature	T _J	150	°C
Storage temperature	T _{stg}	-50~+150	°C

*1 120mW per element must not be exceeded.
*2 200mW per element must not be exceeded.

●Package, marking, and packaging specifications

Part No.	UMA10N	FMA10A
Package	UMT5	SMT5
Marking	A10	A10
Code	TR	T148
Basic ordering unit (pieces)	3000	3000

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{I(off)}	-	-	-0.3	V	V _{CC} =-5V, I _O =-100μA
	V _{I(on)}	-3.0	-	-		V _{CC} =-0.3V, I _O =-20mA
Output voltage	V _{O(on)}	-	-0.1	-0.3	V	I _O /I _C =-10mA/-0.5mA
Input current	I _I	-	-	-7.2	mA	V=-5V
Output current	I _{O(off)}	-	-	-0.5	μA	V _{CC} =-50V, V _I =0V
DC current gain	G _I	33	-	-	-	V _{CC} =-5V, I _O =-5mA
Input resistance	R _I	0.7	1.0	1.3	kΩ	-
Resistance ratio	R ₂ /R ₁	8	10	12	-	-
Transition frequency	f _r	-	250	-	MHz	V _{CC} =-10V, I _E =5mA, f=100MHz *2

*2 Transition frequency of the device.

●External dimensions (Units : mm)

